CD6929B TECHNICAL DESCRIPTION

This unit is powered by an AC-DC converter with 12V DC output. After some necessary regulator circuits, then distribute the power supply to MCU (IC602 GS3011), CD servo (IC601 SA5888), Bluetooth Module (BM81SPK01), Radio receiver (IC301 KT0830EG), Volume control IC (IC401 PT2314), Power amplifier (IC402 TDA8227), and USB charger (IC502 FP6115) respectively. 16.9344MHz crystal (X601) is clock for digital audio while 32.768kHz crystal (X602) is clock for MCU (IC602) and Radio receiver (IC301). Serial EEPROM 24C02 (U602) provides memory backup of MCU (IC602).

CD mode:

When starting up the unit, the software defaults to CD function. MCU issues a Command to start up CD and go into CD mode, also enables the Volume Control IC to work in CD Channel, through CD Mechanism to read and get the data of CD R/RW Disc, and after data processing by MCU, output L&R channel audio signals, and performing volume and EQ control by Volume Control IC, then output to Power Amplifier for amplifying the audio signal and drive the external Speakers.

Radio mode:

Input MCU command by Keyboard and turn to Radio Receiver, and turn on the power supply of Radio Receiver, also enables the Volume Control IC to work in Radio Channel. The clock frequency of Radio Receiver is 32.768kHz, which share the same clock signals with the MCU. It will convert the radio high frequency signals was received into audio signals, and output through the Radio channel of Volume Control IC, then via Power Amplifier to the external Speakers.

Bluetooth mode: (BM81SPK01)

16MHz crystal (X1) provides clock for Bluetooth RF IC (U1 IS1681S). U2 (24C32) is serial EEPROM for parameter backup of Bluetooth RF IC (U1 IS1681S).

Input MCU command by Keyboard, switch to Bluetooth mode, and enables MCU to issue a Command to start up the Bluetooth Module, Volume control IC, power supply of the Power amplifier, and make Volume control IC turn to work in Bluetooth Channel. The Bluetooth Module use a PCB antenna, the clock frequency is 16MHz, and works in the band of 2.4GHz, within the frequency range of 2.402GHz \sim 2.480GHz, Modulation type is GFSK, The Maximum Wireless communications distance up to 10M. The Bluetooth Module will demodulate the Bluetooth RF signals into to Audio signals, and output to the Power Amplifier for amplifying through the Bluetooth Channel of Volume Control IC, and then drives the Speakers by the Amplifier.

Aux mode:

Input the command into the MCU by keyboard, and switch to AUX mode. External Audio signal input to Volume Control IC via 3.5MM Jack for volume and EQ control, and output Audio Signal to Power Amplifier for amplifying, and then drives the Speakers by the Amplifier.

USB Changer:

Supply 5V (Maximum 500mA) from DC/DC converter, and charge to the external device through USB 2.0 Jack.

BlueTooth Module Modulation Type: GFSK Antenna Type: Integral, Internal (PCB Trace) Frequency Range: 2402MHz - 2480MHz, 1MHz channel spacing, 79 channels

Antenna Gain: 0dBi Nominal rated field strength: 94.5dBµV/m at 3m Maximum allowed field strength of production tolerance: +/- 3dB

CH. NO.	FRE.	Hex Value	CH. NO.	FRE.	Hex Value	(CH. NO	FRE.	Hex Value	сн. по	FRE.	Hex Value
CH0	2402MHz	0	CH26	2428MHz	1A		CH52	2454MHz	34	CH78	2480MHz	4E
CH1	2403MHz	1	CH27	2429MHz	1B		CH53	2455MHz	35			
CH2	2404MHz	2	CH28	2430MHz	1C		CH54	2456MHz	36			
CH3	2405MHz	3	CH29	2431MHz	1D		CH55	2457MHz	37			
CH4	2406MHz	4	CH30	2432MHz	1 E		CH56	2458MHz	38			
CH5	2407MHz	5	CH31	2433MHz	1F		CH57	2459MHz	39			
CH6	2408MHz	6	CH32	2434MHz	20		CH58	2460MHz	3A			
CH7	2409MHz	7	CH33	2435MHz	21		CH59	2461MHz	3B			0 20
CH8	2410MHz	8	CH34	2436MHz	22		CH60	2462MHz	3C			
CH9	2411MHz	9	CH35	2437MHz	23		CH61	2463MHz	3D			
CH10	2412MHz	A	CH36	2438MHz	24		CH62	2464MHz	3E			
CH11	2413MHz	В	CH37	2439MHz	25		CH63	2465MHz	3F			
CH12	2414MHz	С	CH38	2440MHz	26		CH64	2466MHz	40			7.
CH13	2415MHz	D	CH39	2441MHz	27		CH65	2467MHz	41			
CH14	2416MHz	E	CH40	2442MHz	28		CH66	2468MHz	42			
CH15	2417MHz	F	CH41	2443MHz	29		CH67	2469MHz	43			0
CH16	2418MHz	10	CH42	2444MHz	2A		CH68	2470MHz	44	o		
CH17	2419MHz	11	CH43	2445MHz	2B		CH69	2471MHz	45			
CH18	2420MHz	12	CH44	2446MHz	2C		CH70	2472MHz	46			
CH19	2421MHz	13	CH45	2447MHz	2D		CH71	2473MHz	47			
CH20	2422MHz	14	CH46	2448MHz	2E		CH72	2474MHz	48			
CH21	2423MHz	15	CH47	2449MHz	2F		CH73	2475MHz	49			
CH22	2424MHz	16	CH48	2450MHz	30		CH74	2476MHz	4A			
CH23	2425MHz	17	CH49	2451MHz	31		CH75	2477MHz	4B			
CH24	2426MHz	18	CH50	2452MHz	32		CH76	2478MHz	4C			
CH25	2427MHz	19	CH51	2453MHz	33		CH77	2479MHz	4D			



BM81SPK01

Bluetooth 3.0+EDR Wireless Speaker Module



Product Description

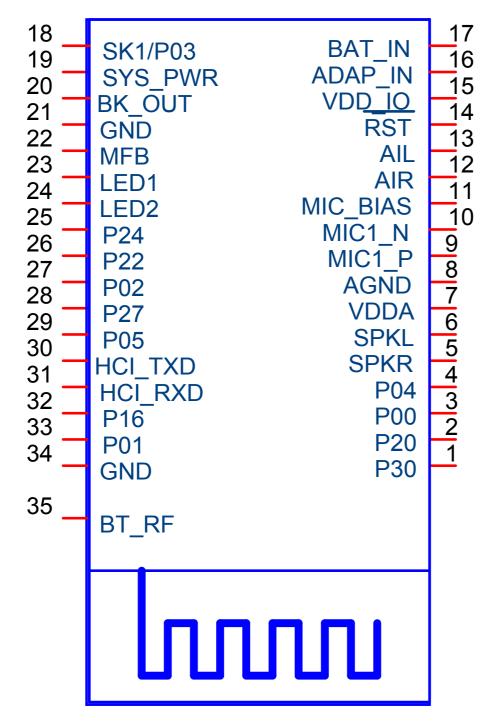
The ISSC BM81SPK01 is a highly integrated Bluetooth 3.0+EDR stereo module, designed for high data rate, short-range wireless communication in the 2.4 GHz ISM band. With ISSC Bluetooth stack and profile, the ISSC BM81SPK01 provides a low power and ultra-low cost Bluetooth 3.0+EDR solution for wireless voice/audio applications.

Features

- Main Chip: ISSC IS1681S
- Bluetooth 3.0+EDR compliant
- Typical +2dBm Class 2 output power
- Receiver Sensitivity: GFSK typical -91dBm, π/4 PSK typical -92dBm, 8DPSK typical -84dBm
- Piconet and Scatter net support
- HCI UART interface
- CVSD, A-law, μ-law CODEC algorithms for voice applications
- SBC decode for Bluetooth audio streaming
- Build-in High performance stereo audio codec
- Cap-less/single end headphone driver
- Audio DAC: 94dB SNR
- Build in Max. 350mAH Li-ion battery charger
- HSP, HFP, A2DP, AVRCP profile support
- 3V operating voltage
- ROM version: 32Kb EEPROM
- 34 pins for DIP module, 35pins for SMT module (with additional 35th pin antenna port for external antenna option)
- Size: 15mm x29mm
- Build-in PCB Antenna
- RoHS compliant



Device Pinout Diagram





Pin Definition

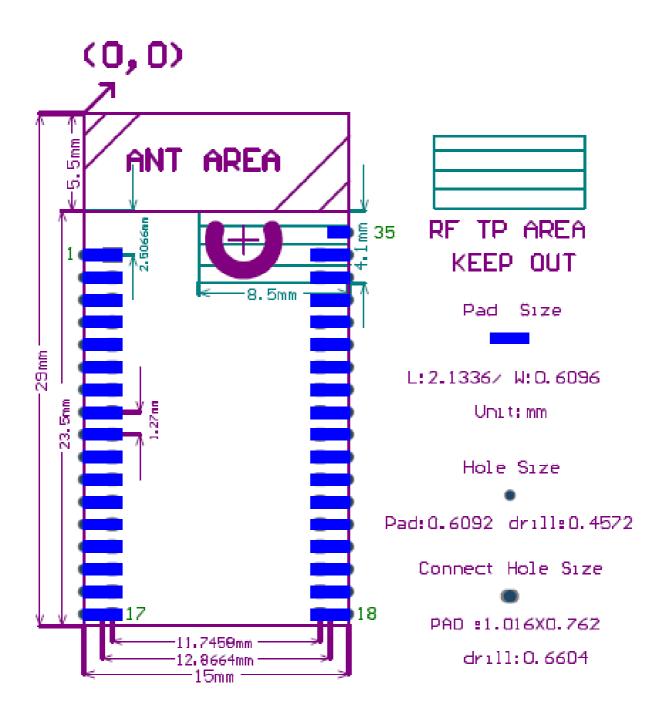
Pin No.	I/O	Name	Description			
			GPIO, default pull-high input			
1	1 P P30		Line-in detection, 1: no line-in detected; 0: line-in			
			detected			
			GPIO, default pull-high input			
2	I/O	P20	System Configuration, H: Application L:			
			Baseband(IBDK Mode)			
3	I/O	P00	GPIO, default pull-low input.			
	"•		Slide Switch Detector			
4	I/O	P04	GPIO, default pull-high input			
			Audio AMP Enable			
5	AO	SPKR	R-channel analog headphone output, single-ended			
		_	application only			
6	AO	SPKL	L-channel analog headphone output, single-ended			
			application only			
7	AP	VDDA	Reserve for external cap to fine tune audio			
0			frequency response			
8	AP		Audio ground			
9	AI	MIC1_P	Mic 1 mono differential analog positive input			
10	AI	MIC1_N	Mic 1 mono differential analog negative input			
11	AP	MIC_BIAS	Microphone biasing voltage			
12	AI	AIR	Stereo analog line in, R-channel			
13 14	AI	AIL	Stereo analog line in, L-channel			
14	I/O	RST_N	System Reset Pin VDDIO pin, for calibration only			
15	Ρ	VDDIO	Do not add external power to this pin			
16	Р	ADAP IN	Power adaptor input			
17	P	BAT IN	Battery input			
			Default SAR input for battery detection			
18	I/O	SK1/P03	This pin can be re-defined as GPIO P03			
19	Р	SYS PW	System Power Output			
20	P	BK OUT	Buck feedback sense pin			
21	P	GND	Digital ground			
·	-					



22	Р	MFB	Multi-Function Push Button key
	Г		Combined Play/Pause key when A2DP enabled.
23	Р	LED1	LED Driver 1
24	Р	LED2	LED Driver 2
25		D04	GPIO, default pull-high input
25	I/O	P24	System Configuration, H: Boot Mode
00		DOO	GPIO, default pull-low input.
26	I/O	P22	External LDO enable
07		DOO	GPIO, default pull-high input
27	I/O	P02	PLAY/PAUSE button
20		D07	GPIO, default pull-high input
28	I/O	P27	Foward button
20			GPIO, default pull-high input
29	I/O	P05	REW button
30	0	HCI_TXD	HCI TX data
31	I	HXI_RXD	HCI RX data
22	I/O	P16	GPIO, default pull-high input
32	1/0	PIO	Volumn down button
22	I/O	D01	GPIO, default pull-high input
33	1/0	P01	Volumn up button
34	Р	GND	Digital ground
25			NC for on board PCB antenna
35	AIO	BT_RF	Antenna matching if an external antenna is used

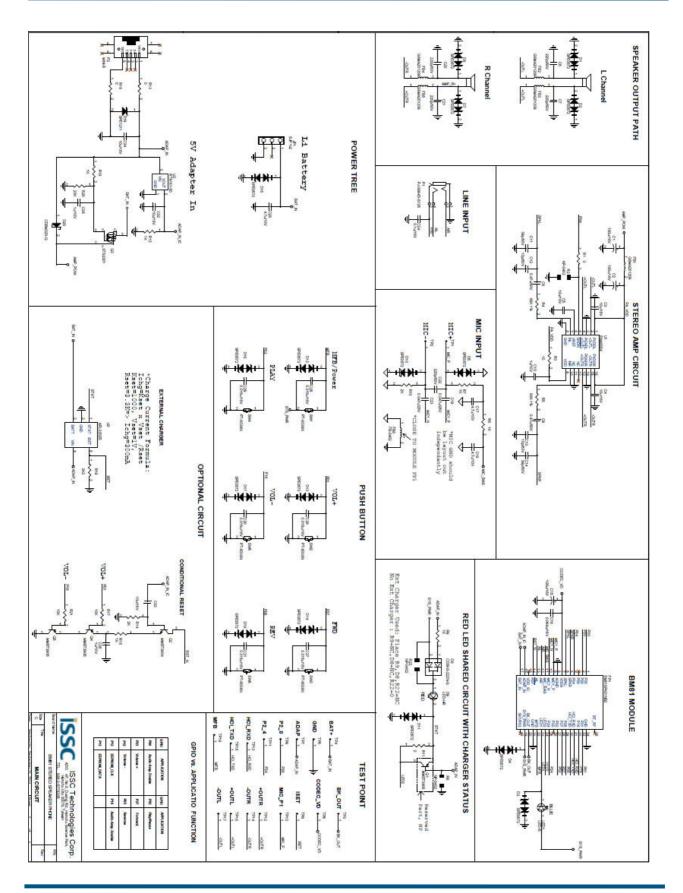


Outline Dimension (Module Foot print)





Preliminary Datasheet BM81SPK01





Bluetooth 3.0+EDR Multimedia SOC

1. General Description

ISSC IS1681S is a compact, high integration, ultra-low cost, CMOS single-chip RF + baseband IC for Bluetooth v3.0+EDR (Enhanced Data Rate) 2.4GHz applications. This chip is fully compliant with Bluetooth specification and completely backward-compatible with Bluetooth 1.1, 1.2, 2.0 or 2.1 systems.

It incorporates Bluetooth 1M/2M/3Mbps RF, single-cycle 8051, TX/RX modem, memory controller, task/hopping controller, UART interface, and ISSC Bluetooth software stack to achieve the required Bluetooth v3.0+EDR functions.

The IS1681S is designed to support high quality audio applications, an audio engine and a high performance stereo CODEC are integrated for this purpose.

The audio engine provides the A-law/µ-law/CVSD voice encoding/decoding and also the SBC audio decoding. hanced noise reduction and echo cancellation to offer the best voice quality in the both sending and receiving sides.

In addition, to minimize the external components required for portable devices, a voltage sensor for battery, Li-ion battery charger, a switching regulator and LDOs are integrated to reduce BOM cost for various Bluetooth applications.

The device incorporates built-in self-test (BIST) and auto-calibration functions to simplify production test.



2. Features

System Specification

• Compliant with Bluetooth Specification v.3.0 + EDR in 2.4 GHz ISM band

Baseband Hardware

- 16MHz main clock input
- Built-in internal ROM for program memory
- Built-in 32 KB RAM for data storage and baseband data transfer buffering
- Enhanced Power Control
- Bluetooth 2.1 features
 - Encryption Pause and Resume
 - Erroneous Data Reporting
 - Extended Inquiry Response
 - Link Supervision Timeout Changed Event
 - Non-Flushable Packet Boundary Flag
 - Secure Simple Pairing
 - Sniff Subtracting
- Support both Pico-net and Scatter-net applications
- Hard-wired logic for modulation, demodulation, access code correlation, whitening, forward error correction (FEC), header error check (HEC), shorten hamming code, CRC generation/checking, frame check sequence (FCS), encryption bit stream generation, and transmit pulse shaping
- Adaptive Frequency Hopping (AFH) avoids occupied RF channels



• Fast Connection supported

RF Hardware

- Fully Bluetooth 3.0 + EDR system in 2.4 GHz ISM band.
- Combined TX/RX RF terminal simplifies external matching and reduces external antenna switches.
- Max. +4dBm output power with 20 dB level control from register control.
- Build-in T/R switch for Class 2/3 application
- Build-in channel filter.
- To avoid temperature variation, temperature sensor with temperature calibration is utilized into bias current and gain control.
- Fully integrated synthesizer has been created. There requires no external VCO, varactor diode, resonator and loop filter.
- Crystal oscillation with build-in digital trimming for temperature/process variations.

Audio processor

- Support 64 kb/s A-Law or μ-Law PCM format, or CVSD (Continuous Variable Slope Delta Modulation) for SCO channel operation.
- Noise suppression
- Echo suppression
- SBC decoding
- Packet error concealment

Audio Codec

• 16 bit stereo codec



- 94dB SNR DAC playback
- Integrate headphone amplifier for 16Ω speakers

Peripherals

- Built-in Lithium-ion battery charger
- Integrate 3V, 1.8V LDO and Switching mode regulator
- Built-in 10-bit Aux-ADC for battery monitor and voltage sense.
- LED driver

Flexible HCI interface

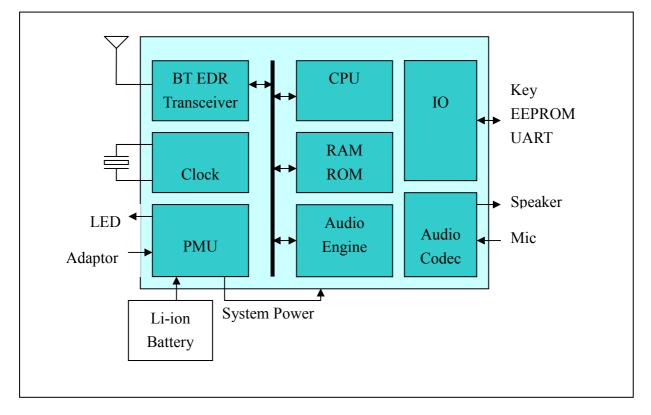
• High speed HCI-UART (Universal Asynchronous Receiver Transmitter) interface

Package

• 7x7mm² 56 pins, 0.4mm pitch SAW QFN standard package

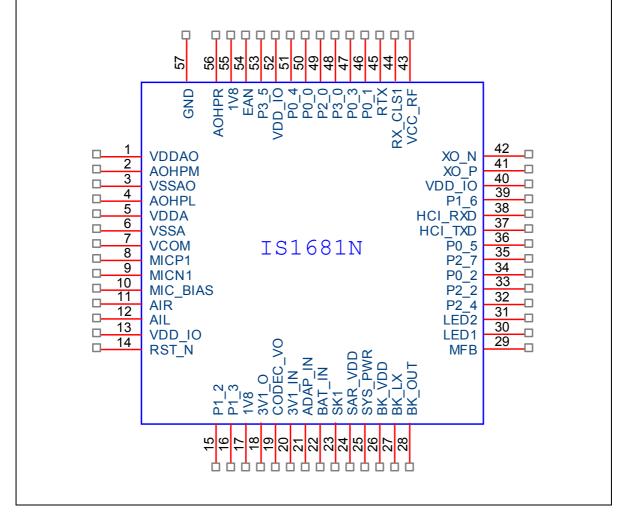


3. Functional Diagram





4. Pin Assignment





5 Pin Descriptions

Pin No.	I/O	Pin Name	Pin Descriptions
1	Р	VDDAO	Positive power supply dedicated to CODEC output
0			amplifiers.
2	AO	AOHPM	Headphone common mode output/sense input
3	Ρ	VSSAO	Negative power supply dedicated to CODEC output amplifiers
4	AO	AOHPL	L-channel analog headphone output
5	Р	VDDA	Positive power supply/reference voltage for CODEC
6	Ρ	VSSA	Negative reference/power supply for CODEC
7	AO	VCOM	Internal biasing voltage for CODEC
8	AI	MICP1	Mic 1 mono differential analog positive input
9	AI	MICN1	Mic 1 mono differential analog negative input
10	Р	MIC_BIAS	Electric microphone biasing voltage
11	AI	AIR	R-channel single-ended analog inputs
12	AI	AIL	L-channel single-ended analog inputs
13	Р	VDD_IO	I/O power supply input
14	A 1	DOT N	KEY PIN for FT Test
14	AI	RST_N	System Reset Pin
			GPIO, default pull-high input
15	I/O	P1 2	KEY PIN for FT Test
15	1/0	F 1_2	EEPROM clock SCL
			Clock signal for OLED
			GPIO, default pull-high input
16			KEY PIN for FT Test
10	1/0	P1_3	EEPROM data SDA
			Data signal for OLED
17	Ρ	1V8	Core 1.8V power input
18	Р	3V1_0	3.1V LDO output
19	Р	CODEC_VO	3.1V LDO output for CODEC power
20	Р	3V1_VIN	3.1V LDO input
21	Р	ADAP_IN	Power adaptor input
22	Р	BAT_IN	Battery input



Pin No.	I/O	Pin Name	Pin Descriptions
23	AI	SK1	ADC analog input 1
24	Р	SAR_AVDD	SAR 1.8V input
25	Р	SYS_PWR	System Power Output
26	Р	BK_VDD	Buck VDD Power Input
27	Р	BK_LX	Buck feedback input
28	Р	BK_OUT	Buck output
29	Р	MFB	Multi-Function Push Button key, push high
30	AI	LED1	LED Driver 1
31	AI	LED2	LED Driver 2
			GPIO, default pull-high input
32	I/O	P2_4	KEY PIN for FT Test
			System Configuration, H: Boot Mode
			GPIO, default pull-low input.
33	I/O	P2_2	Keep alive for external LDO power enable
			application.
34	I/O	P0_2	GPIO, default pull-high input
54	20	FU_2	Play/Pause key as the default setting
			GPIO, default pull-high input
35	I/O	P2_7	FWD key when class 2 RF
			FWD key(short press) when class 1 RF
			GPIO, default pull-high input
36	I/O	P0 5	KEY PIN for FT Test
50	1/0	10_5	REV key when class 2 RF
			REV key(short press) when class 1 RF
37	Ο	HCI_TXD	KEY PIN for FT Test
07)		HCI TX data
38	I	HCI_RXD	KEY PIN for FT Test
00	•		HCI RX data
			GPIO P1_6, default pull-high input
39	I/O	P1_6	Volume down key when class 2 RF
			Audio AMP Enable when class 1 RF
40	Р	VDD_IO	I/O power supply input
41	Ι	XO_P	16MHz Crystal input positive



Pin No.	I/O	Pin Name	Pin Descriptions
42	Ι	XO_N	16MHz Crystal input negative
43	RP	VCC_RF	RF power input for both synthesizer and TX/RX block
44	Ι	RX_CLASS1	Class1 RF RX path
45	I/O	RTX	Class2 RTX path; Class1/Class2 TX path
			GPIO, default pull-high input
46	I/O	D0 1	Volume up key when class 2 RF.
40	1/0	P0_1	Class1 Control signal of external TR switch when
			class 1 RF
			GPIO, default pull-high input
47	I/O	D0 2	KEY PIN for FT Test
47	1/0	P0_3	Class1 Control signal of external TR switch when
			class 1 RF
48	I/O		GPIO, default pull-high input
40	1/0	P3_0	Reverved charger LED driver
			GPIO, default pull-high input
49	I/O		KEY PIN for FT Test
49	1/0	P2_0	System Configuration, H: Application L:
			Baseband(IBDK Mode)
			GPIO, default pull-low input.
50	I/O	P0_0	KEY PIN for FT Test
			Slide Switch Detector
51	I/O		GPIO, default pull-high input
51	1/0	P0_4	Audio AMP Enable when class 2 RF
52	Р	VDD_IO	I/O power supply input
53	I/O	P3_5	GPIO 3_5, default pull-high input.
55	1/0	F3_5	Buzzer Signal Output
54		EAN	Embedded ROM/External Flash enable
54	I		H: Embedded; L: External Flash
55	Р	1V8	Core 1.8V power input
56	AO	AOHPR	R-channel single ended analog headphone output
57	Ρ	GND	Exposed pad as ground



Application Note for GPIO Setting:

- 1) KEY PIN for internal test HCI RXD, HCI TXD, RST N, P2 0, P2 4, P1 3, P1 2, P0 3, P0 5, P0 0
- 2) For Class2 RF application: VOL+:P0_1, VOL-: P1_6, FWD:P2_7, REV:P0_5, AUDIO AMP ENABLE: P0_4
- 3) For Class1 RF application: VOL+:P2_7(Long Press), VOL-: P0_5(Long Press), FWD:P2_7(Short Press), REV: P0_5(Short Press), AUDIO AMP ENABLE: P1_6
- 4) Play/Pause: P0_2
- 5) P1_2:EEPROM Clock/Clock Signal for OLED P1_3:EEPROM Data/Data Signal for OLED
- 6) Slide switch detect: P0_0
- 7) Buzzer Signal Output: P3_5
- 8) Class 1 RF TX: P0_1, CLASS 1 RF RX: P0_3
- 9) External LDO power enable keep alive: P2_2
- 10)System Configuration: P2_0, P2_4



6 Functional Description

6.1 Overall Architecture

The ISSC IS1681S integrates an enhanced EDR Bluetooth RF & BB core, HCI controller, audio engine and an ENHANCED 8051 processor with an internal mask ROM for program memory and SRAM for data memory. An innovative interconnection structure called the Common-Memory Architecture (CMA) is designed to provide a fast and flexible data movement scheme between the embedded processor, Bluetooth core, and peripheral hardware.

For audio application and power management, IS1681S has build-in an audio processor, mono codec and power management unit to reduce the external components.

6.2 Radio Frequency (RF)

6.2.1 Transmitter

The internal PA has a maximum output power of +4dBm with level control 20dB from amplitude control. This is applied into Class 2/3 radios without external RF PA. For Class1 application, the build-in level control can be used with external PA for power control requirement.

The transmitter features IQ direct conversion to minimize the frequency drift. And it can excess 30dB power range with temperature compensation machine.

6.2.2 Receiver

The LNA can be operated into two type modes. One type is TR-combined mode for single port application. The other type is TR-separated mode for external PA/LNA application.



An ADC is used to sample input analogue wave for digital demodulation. Before the ADC, a channel filter has been integrated into receiver channel to increase the anti-interference capacity and also reduce the external component count.

For avoiding temperature variation issues, a temperature sensor with temperature calibration is utilized into bias current and gain control of LNA, Mixers, and RF AMP.

6.2.3 Synthesizer

The internal loop filter is used to reduce external RC components. This can reduce cost and variations for components. This internal LC tank for VCO is utilized to reduce variation for components. The cost is down at the same time.

A fully integrated synthesizer has been created. There requires no external VCO, varactor diode, resonator and loop filter.

6.3 MODEM

There are three different modulations for Bluetooth v3.0 + EDR. Table 6.3 summarizes these modulations and data rate.

Data Rate	Modulation	Bits/Symbol
BDR: 1 Mbps	GFSK	1
EDR: 2 Mbps	π/4 DQPSK	2
EDR: 3 Mbps	8DPSK	3

Figure 6.3 Modulation type for Bluetooth v3.0 + EDR



6.3.1 Basic Data Rate MODEM (BDR)

On the Bluetooth v1.2 specification and below, 1 Mbps was the standard data rate based on Gaussian Frequency Shift Keying (GFSK) modulation scheme. This basic rate modem meets BDR requirements of Bluetooth v3.0+EDR specification.

Figure 6.3.1 Data format for BDR

Access Code	Header	Payload
-------------	--------	---------

6.3.2 Enhanced Data Rate MODEM (EDR)

On the Bluetooth v3.0+EDR specification, Enhanced Data Rate (EDR) has been introduced to provide 2 and 3 Mbps data rates as well as 1 Mbps. This enhanced data rate modem meets EDR requirements of Bluetooth v3.0+EDR specification. For the viewpoint of baseband, both BDR and EDR utilize the same 1MHz symbol rate and 1.6 KHz slot rate. For BDR, 1 symbol represents 1 bit. However each symbol in the payload part of EDR packets represents 2 or 3 bits. This is achieved by using two different modulations, $\pi/4$ DQPSK and 8DPSK.

Figure 6.3.2.A Data format for EDR

Access Code Hea	ader Guard	Sync	Payload	Trailer	
-----------------	------------	------	---------	---------	--

For $\pi/4$ DQPSK modulation, each symbol carries 2 bits of information. For its constellation diagram, although there are 8 possible phase states, the encoding scheme guarantees the trajectory of the modulation between symbols is restricted to 4 states. For a given starting



point, every phase change between symbols is restricted to +45°, +135°, -45°, and -135°.

Phase Shift	Bit Pattern
+45° (+π/4)	00
+135° (+3π/4)	01
-135°(-3π/4)	11
-45°(-π/4)	10

Figure 6.3.2.B Phase shift & bit pattern for 2 MHz data rate

For 8DPSK modulation, each symbol carries 3 bits of information. For its constellation diagram, it is similar to $\pi/4$ DQPSK but the trajectory of the modulation between symbols has 8 possible phase states. For a given starting point, every phase change between symbols is restricted to 0°, +45°, +90°, +135°, +180°, -135°, -90°, and -45°.

Figure 6.3.2.C Phase shift & bit pattern for 3 MHz data rate

Phase Shift	Bit Pattern
0° (+0)	000
+45° (+π/4)	001
+90° (+π/2)	011
+135° (+3π/4)	010
+180° (+π)	110
-135° (-3π/4)	111
-90° (-π/2)	101



-45° (-π/4)	100
-------------	-----

6.4 Baseband

The following modules implemented in hardware constitute the Bluetooth Baseband Core. The frequency hopping sequence generator produces the correct hop frequency control sequence based on the Bluetooth clock, Bluetooth device address, and the current operating mode.

The access code generates the access code based on the Lower Address Part (LAP) of the Bluetooth device address. The access code is comprised of the preamble, sync word and trailer bits. The detection of the access code uses correlation to detect a valid access code.

Bluetooth uses two types of FEC: 1/3 repetition code and (15, 10) shorten Hamming code respectively. The former basically repeats each transmitted bit three times while the latter has 15 bits of codeword which contains 5 parity bits. The code has capability of correction of all single-bit errors in each codeword.

The purpose of HEC is to protect the header bits. Dedicated header error code generator calculates the HEC bits in the header of a transmitted packet. While on the receiver side, HEC detects corrupted headers.

A 16-bit CRC is adopted to protect payload data transmitted using certain types of Bluetooth packets.

Information confidentiality can be protected by encryption of the packet payload. Dedicated encryption/decryption hardware is designed into the baseband core.



6.5 MCU

The embedded processor for IS1681S is a single-cycle 8051 CPU. The embedded processor will be referred to as simply the processor, 8051, or MCU throughout the remainder of this document. There are a few minor differences between a standard 8051 and this CPU. These include:

- 1. Alteration of memory timings to match internal and external memory configurations.
- 2. Modification of idle mode to disable internal CPU clocking. Only externally-clocked interrupt sources can allow the CPU to recover from idle mode.

A single-port synchronous interface is provided to memory. From this single port, the bandwidth is divided among the 7 interfaces spread amongst 5 physical busses described below:

- Embedded processor bus
- Baseband TX bus
- Baseband RX bus
- HCI TX bus
- HCI RX bus
- Audio bus
- DMA bus

In addition, attached to the embedded processor bus are a register bank, a dedicated single-port memory (data segment 1), and flash memory (program segment). The processor coordinates all link control procedures and data movement using a set of pointer registers. For example, when an HCI packet (from the host via USB or UART) is received into the HCI buffer, the processor is interrupted. The processor can then read a



status register to determine the HCI packet type and determine whether to set up the Baseband pointer registers for this memory region for RF-retransmission, or to otherwise directly perform packet processing with the CPU.

6.6 Bluetooth Clock and Timers

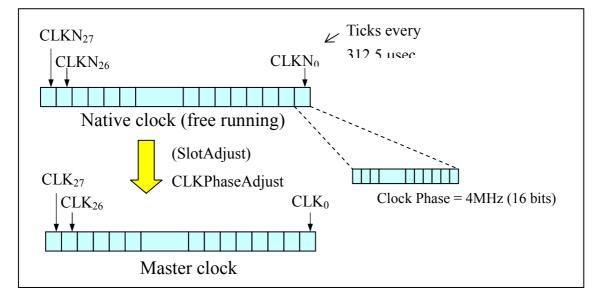
A Bluetooth standard 28-bit counter running at 3.2 kHz implements the native clock defined by Bluetooth specification. This clock provides the transmission and receiving timing of a half time slot (312.5 μ s). Another finer counter implemented in 16 bits is also provided as the phase of a half time slot. This phase information is very helpful when a Bluetooth slave wants to adapt to its master's clock. The counter is pre-scalable for the purpose of power saving operations. The diagram below describes a standard Bluetooth native clock and master clock. The clock signal is also used as a slot boundary signal to trigger a baseband packet transmission or receipt.

There are several timers provided by the system, two timers for TX/RX and the others for general purpose.

The powerful pre-scheduling functions for the transceiver are realized different sets of programmable timers. Each set of timers is associated with the task of transmission or receiving. When the timer is configured by firmware, it will automatically execute the TX or RX task at a specific time. Sub-tasks and timing for a TX task remain to be defined.



Figure 6.6 Bluetooth clock



6.7 HCI Control Logic for USB/UART

Hardwired control logic is presented in front of the UART devices for HCI protocol handling and packet buffering. This control logic is part of the HCI controller defined in Bluetooth specification 1.2. This logic is partially responsible for the HCI protocol handling to/from the host and it also maps the registers of the UART devices indirectly to the 8051 such that the system can receive or send a HCI packet to/from the respective host interface. Major functions of this logic include:

- HCI packet formatter and de-formatter (identifying the packet type)
- Frame boundary determination, segmentation and reassembly of HCI packets.
- HCI packet transmission, receiving, and buffering (using common memory HCI buffer).
- Independent receive / transmit channels
- Universal device interface



6.7.1 HCI UART Interface

An embedded HCI UART (Universal Asynchronous Receiver Transmitter) with programmable data rate up to 3Mbps is included in this design. The HCI UART supports the following functions:

- Full-Duplex operation
- Programmable BAUD rate (using 16-bit input clock divider to obtain Baud Rate x16 or x24 or x13 clock base)
- 7 or 8 Data bits
- 1 or 2 Stop bits
- Even / Odd / Mark / Space / None Parity configurations
- Break Generation / Detection
- Maskable individual interrupts to CPU and combined Error interrupt to HCI
- Selectable Direct CPU interface or interface to HCI module

6.8 General Purpose I/O

The IS1681S provides 14 general purpose I/O ports. These general I/Os can be defined as input or output port individually by setting specific register bit. While setting as an input port, a build-in 50K Ω pull high or pull low resistor can be enabled for different application purpose.

6.9 Audio Processor

The IS1681S builds in an enhanced audio engine to offer high quality of audio for voice application. The standard A-law/ μ -law/CVSD voice functions are implemented in the audio engine. The enhanced audio functions, like AEC, noise reduction, can be achieved with

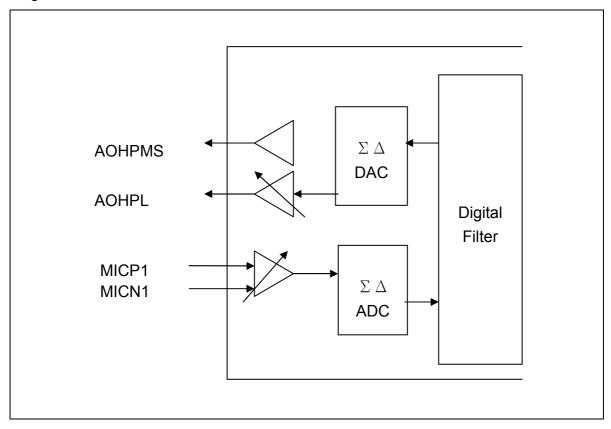


enhanced algorithm.

6.10 Audio Codec

The build in codec contains a analog to digital convert (ADC), a digital to analog converter (DAC) and additional analog circuits like headphone driver and microphone amplifier.

Figure 6.10 Audio Codec



6.10.1 ADC

The ADC interface supports variety sampling rate from 8k Hz to 48k Hz. The microphone input has 42 dB programmable analog gain and 48db digital gain. A regulated MIC_Bias is available.



6.10.2 DAC

The DAC output is available for both line level and through the headphone amplifier to drive a low impedance headphone. The headphone output volume is adjustable by the combination of the digital/analog gain control.

6.11 Auxiliary ADC

The 10-bit auxiliary analog to digital converter (SAR ADC) provides one dedicated channel for battery power detection and one other channel for external peripheral sensing. This ADC has 10 bits resolution that provides an accurate monitoring for battery voltage. The operating current is very low and almost consumes no power when disabled.

6.12 Power Management (PMU)

The power management unit of IS1681S includes several power control blocks, linear regulators, switch-mode regulator, Aux-ADC, LED driver and Lithium-ion/Polymer battery charger.

6.12.1 3V1_LDO

The IS1681S has build-in the programmable output voltage LDOs (1.8~3.2V) for codec and digital IO power supply. The programmable LDO is used to regulate the high input voltage from battery or adapter. This LDO needs 1uF bypass capacitor.

6.12.2 Buck regulator

The built-in programmable output voltage buck (1.8~2.4V) converts battery voltage for RF and baseband core power supply. This converter has high conversion efficiency and fast



transient response.

6.12.3 Aux-ADC

The 10-bit Successive-Approximation analog to digital converter (SAR ADC) monitors the battery power and adapter power for charging and power management control.

6.12.4 Li-ion Battery Charger

IS1681S includes a built-in battery charger optimized for use with lithium polymer batteries. The charger features a current sensor for charging control, user programmable current regulation and high accuracy voltage regulation. It charges the battery in four phases:

- reviving mode : 2mA charging current to charge BAT to 2.5V
- pre-charge mode : 0.1C charging current to charge BAT to 3.0V
- constant current mode : 0.xC (default 0.7C) charging current to charge BAT to 4.2V (programmable)
- constant voltage mode : charging is terminated while the charging current drops below 0.YC (default 0.13C)

Charging current in the constant current mode can be configured to provide a wide range of charging current up to 180mA (1mA per step). Charger will re-start charging if the battery voltage falls below an internal threshold.

System operation is allowed when the battery is charging.

6.13 Miscellaneous (Watchdog Timer, and Clock Divider)

System related functions such as watchdog timer, Endian control, and interrupt vectors are



also provided. The purpose of the watchdog timer is to provide a reset to CPU in case when the CPU fails to service the watchdog timer in a pre-defined (programmable) period.



7 Electrical Characteristics

Absolute Maximum Ratings

Rating	Min	Max	Max	
Operation Temperature		-40°C	+85°C	°C
	VDD_CORE, VCC_RF,			
Core supply voltage	AVDD_SAR,	1.7V	1.98V	V
	AVDD_PLL			v
Codec supply voltage	VDD_AUDIO		3.3	V
I/O voltage	VDD_IO		3.3	V
	BK_VDD		4.7	V
Supply voltage	3V1_VIN		5	V
	BAT_IN		4.3	V
	ADAP_IN		6	V
	LED[1:0]		5	V
	Power switch		6	V

Recommended Operate Condition

Symbol	Parameter	Min	Typical	Мах	Unit
V _{DD18}	Digital core supply voltage				
	SAR ADC supply voltage	1.62	1.8	1.92	V
	CODEC supply voltage				
V _{DDIO}	I/O supply voltage	2.5 2.7		2.2	V
	RF supply voltage			3.3	
TOPERATION	Operating temperature range	-20	+25	+70	°C
T _{stg}	Storage temperature	-40		+125	°C
V _{LDO}	LDO supply voltage	1.8		3.3	V
V _{BAT_IN}	Input voltage for SAR ADC	0.9		3.3	V



Radio Characteristics:

Transmitter section for BDR

VCC_RF = 2.7V 25°C	Temperature =	Min	Тур	Мах	Bluetooth specification	Unit
Maximum RF transmit power			3	4.0	-6 to 4	dBm
RF power variation over temperature range with compensation enabled			±2			dB
RF power control range			20		≥16	dB
RF power range cor	ntrol resolution		0.5			dB
20dB bandwidth for	modulated carrier		900		≤1000	KHz
ACP	$F = F_0 \pm 2MHz$		-28		≤-20	dBm
	$F = F_0 \pm 3MHz$		-46		≤-40	dBm
Note: F ₀ =2441MHz	$F = F_0 \pm >3MHz$		-54		≤-40	dBm
Δf_{1avg} maximum modulation		150		165	140<∆f _{1avg} <17 5	KHz
Δf_{2max} maximum modulation		140		150	≥115	KHz
$\Delta f_{2avg}/\Delta f_{1avg}$		0.95	1		≥0.80	
ICFT (abs)		0	5	10	75	KHz
Drift rate (abs)		2		7	≤20	KHz/50u
						S
Drift (single slot packet, abs)			12		≤25	KHz
2 nd harmonic content @ Tx= 4dBm			-53		≤-47	dBm
3 rd harmonic content @ Tx= 4dBm			-55		≤-47	dBm



Receiver section for BDR

Temperature = 25°C	Frequency (GHz)	Min	Тур	Max	Bluetooth specification	Unit
Sensitivity at 0.1% BER for all basic rate packet types	2.402		-91			
	2.441		-91		≤-70	dBm
	2.480		-91			
Maximum received signal at 0.1% BER			-10		≥-20	dBm
C/I co-channel			5		≤11	dB
Adjacent channel selectivity C/I Note: F ₀ =2441MHz	F = F ₀ +1MHz		-7		≤0	dB
	F = F ₀ -1MHz		-7		≤0	dB
	F = F ₀ +2MHz		-36		≤-30	dB
	F = F ₀ -2MHz		-22		≤-9	dB
	F = F ₀ -3MHz		-24		≤-20	dB
	F = F ₀ +5MHz		-50		≤-40	dB
	F = F _{image}		-22		≤-9	dB
Maximum level of intermodulation interferers			-38		≥-39	dB



Transmitter Section for EDR

Temperature = 25°C		Min	Тур	Мах	Bluetooth specification	Unit
Relative transmit powe	r		-1.6		-4 to 1	dB
	ω _o freq. error		5		≤10 for all blocks	KHz
π/4 DQPSK max carrier frequency stability	ω _i initial freq. error		10		≤75 for all blocks	KHz
Stability	ω₀+ω _i block freq. error		10		≤75 for all blocks	KHz
	ω₀ freq. error		5		≤10 for all blocks	KHz
8DPSK max carrier frequency stability	ω _i initial freq. error		10		≤75 for all blocks	KHz
	ω _o +ω _i block freq. error		10		≤75 for all blocks	KHz
	RMS DEVM		7		≤20	%
π/4 DQPSK modulation accuracy	99% DEVM		Pass		≤30	%
@ Tx= 2dBm	Peak DEVM			25	≤35	%
8DQPSK modulation	RMS DEVM		7		≤13	%
accuracy @ Tx= 2dBm	99% DEVM		Pass		≤20	%
	Peak DEVM			20	≤25	%



Preliminary Datasheet

	$F > F_0+3MHz$	<-54	≤-40	dBm
	F = F ₀ -3MHz	-46	≤-40	dBm
In-band spurious	$F = F_0$ -2MHz	-28	≤-20	dBm
emissions	$F = F_0$ -1MHz	-30	≤-26	dBm
Note: F ₀ =2441MHz	$F = F_0 + 1MHz$	-30	≤-26	dBm
	$F = F_0 + 2MHz$	-28	≤-20	dBm
	$F = F_0 + 3MHz$	-46	≤-40	dBm
EDR differential phase	encoding	100	≥99	%



Receiver Section for EDR

Temperature = 25°C	Frequenc y (GHz)	Modulatio n	Min	Тур	Max	Bluetooth specificatio n	Unit	
	2.402	π/4 DQPSK		-92				
	2.441	π/4 DQPSK		-92		≤-70	dBm	
Sensitivity at 0.019 BER	2.480	π/4 DQPSK		-92				
	2.402	8DPSK		-84				
	2.441	8DPSK		-84		≤-70	dBm	
	2.480	8DPSK		-84			l	
Maximum received si	gnal at 0.1%	π/4 DQPSK		-10		≥-20	dBm	
BER		8DPSK		-10		≥-20		
C/I co-channel at 0.1	% BER	π/4 DQPSK		4		≤13	dB	
		8DPSK		5		≤21	dB	
	$F = F_0 + 1MHz$	π/4 DQPSK		-14		≤0	dB	
		8DPSK		-8		≤5	dB	
Adjacent channel selectivity C/I	F = F ₀ -1MHz	π/4 DQPSK		-13		≤0	dB	
		8DPSK		-8		≤5	dB	
Note: F ₀ =2441MHz	$F = F_0 + 2MHz$	π/4 DQPSK		-38		≤-30	dB	
		8DPSK		-34		≤-25	dB	
	F = F ₀ -2MHz	π/4 DQPSK		-21		≤-7	dB	



Preliminary Datasheet

	8DPSK	-21	≤0	dB
F = F ₀ -3MHz	π/4 DQPSK	-27	≤-20	dB
	8DPSK	-20	≤-13	dB
$F = F_0 + 5MHz$	π/4 DQPSK	-52	≤-40	dB
	8DPSK	-45	≤-33	dB
F = F _{image}	π/4 DQPSK	-21	≤-7	dB
	8DPSK	-21	≤0	dB



Audio Codec: ADC

Test Condition:						
T= 25°C, Vdd=2.8V, 1KHz	z sine wave input, Ba	ndwidth = 20	0~20KHz	2		
Parameter	Conditio	n	Min.	Тур.	Max.	Unit
Input full-scale	Full scale (lir	ie-in)			2.2	Vpp
Resolution				16		bits
Input Sampling Rate			8		48	kHz
SNR	f _{in} =1KHz	8KHz		83		
	B/W=20~20KHz A-weighted	16KHz		83		
	THD+N < 1% 150mVpp input	32KHz		83		dB
		44.1KHz		83		
		48KHz		83		
SNR	A-weighted 1KHz@	full scale,		75		dB
	Microphone boos	st enable				
THD+N (Mic input)				0.04		%
@30mVrms input						
THD+N (line input)				0.01		%
Mic Boost Gain				20		dB
Digital Gain			-54		4.85	dB
Analog Gain					26	dB
Digital Gain Step				6		dB
Analog Gain Step				1.7		dB
Input impedance	Input impeda	ance		6	10	KΩ
(microphone mode)	Input capacit	ance			20	pF
Analog supply voltage (AVDD)			1.8	2.8	3.0	V



Audio Codec: DAC

Test Condition: T= 25°C, V	Test Condition: T= 25°C, Vdd=2.8V, 1KHz sine wave input, Bandwidth= 20~20KHz						
Parameter	Conditio	on	Min.	Тур.	Max.	Unit	
Output Level	Full sca	le		2.1		Vpp	
Resolution			16			bits	
Output Sampling Rate			8		48	KHz	
SNR	f _{in} =1KHz	8KHz		94		dB	
	B/W=20~20KHz A-weighted	16KHz		94		dB	
	THD+N < 0.01%	32KHz		94		dB	
	0dBFS signal	44.1KHz		94		dB	
	Load=100KΩ	48KHz		94		dB	
Max Output Power	R _L =160h	nm		35		mW	
	R _L =320ł	nm		17		mW	
THD+N	160hm lo	bad			0.05	%	
	100K Ω I	oad			0.01	%	
Digital Gain			-54		4.85	dB	
Digital Gain Resolution				6		dB	
Analog Gain			-28		3	dB	
Analog Gain step				1		dB	
Output resistance	RL		8	16		Ohm	
Output capacitance	Ср				500	pF	
Crosstalk between	L vs. R, measured at			00	00	٩D	
channels	-10dBFS@1KHz input			-90	-80	dB	
Analog supply voltage (AVDD)			1.8	2.8	3.0	V	



Battery Charger

Charging Mode (BAT_IN	rising to 4.2V)	Min	Тур	Max	Unit
Operation Temperature		-20		70	°C
Input Voltage (Vin)					
Note: It needs more time t	o get battery fully	4.5		6	V
charged when Vin=4.5V					
Battery trickle charge cu	ırrent		0.1C		mA
(BAT_IN < trickle charge v	voltage threshold)		0.10		
Trickle charge voltage th	ckle charge voltage threshold		3		V
Maximum battery	Headroom > 0.7V		350		mA
charge current	Headroom = 0.3V		150		mA
Minimum battery	Headroom > 0.7V		1		mA
charge current	Headroom = 0.3V		1		mA
Battery charge terminati	on current,		10		%
% of fast charge current			10		70
Battery recharge hysteresis (Note1)			100		mV
Battery recharge current (Note2)			0.25C		mA
Note: C \rightarrow Battery capacit	.y		0.200		

- Note1: When charging complete and the adapter is still in, the battery voltage will slowly drop down. When the voltage drop is larger than 100mV from the full voltage, the re-charging cycle will start.
- Note2 : If the battery voltage during plug in is larger than 4V, the charging current will be limited to 0.25C to avoid the battery voltage overshoot.



Switching Regulator

Normal Operation		Min	Тур	Max	Unit
Operation Temperature		-20		70	°C
Input Voltage (Vin)		3	3.7	4.5	V
Output Voltage (Vout)		1.6	1.85	2.4	mA
Output Ripple				20	mVrms
Max. Average Load Current(Iload)		120			mA
Max. Output Current (pea	ık)	200			mA
	I _{load} =50mA		88		
Conversion Efficiency (Bat.@3.7V)	I _{load} ≥ 10mA		80		%
(Bat.@3.7V)	I _{load} ≥ 250uA		65		
Switching Frequency			800		KHz
Start-up current Limit		0	50	210	mA
Start-up Settling Time			1.2	2	ms
Shutdown Current				<1	uA



LDO

Normal Operation		Min	Тур	Max	Unit
Input Voltage (Vin)		3.0		4.5	V
Output Voltage (V _{OUT})	V _{OUT} = 2.9V (2.4~3.4V)		2.9		N
(1) V _{OUT_CODEC} (2) V _{OUT_IO}	V _{OUT} = 1.8V (1.3~2.3V)		1.8		- V
Accuracy (V _{IN} =3.7V, I _{LC}	_{DAD} =100mA, 27'C)		±5		%
Output Voltage adjusta	able step		100		mV/Step
Output adjustment rar	put adjustment range		±0.5		V
Start-up inrush curren	t		200	200 400 mA	
Start-up Settling Time			250	500	μs
Output current(averag	e)			100	mA
Output Current(peak)				150	mA
Drop-out voltage (I _{load} = current)	= maximum output			300	mV
Quiescent Current			45		μA
(excluding load, I _{load} < 1mA)					P., 7
Load Regulation (I _{load} = 0mA to 100mA), Δ Vout				80	mV
Shutdown Current				<1	μΑ

Note: Two 100mA LDOs, one for IO and one for audio CODEC.



Clock

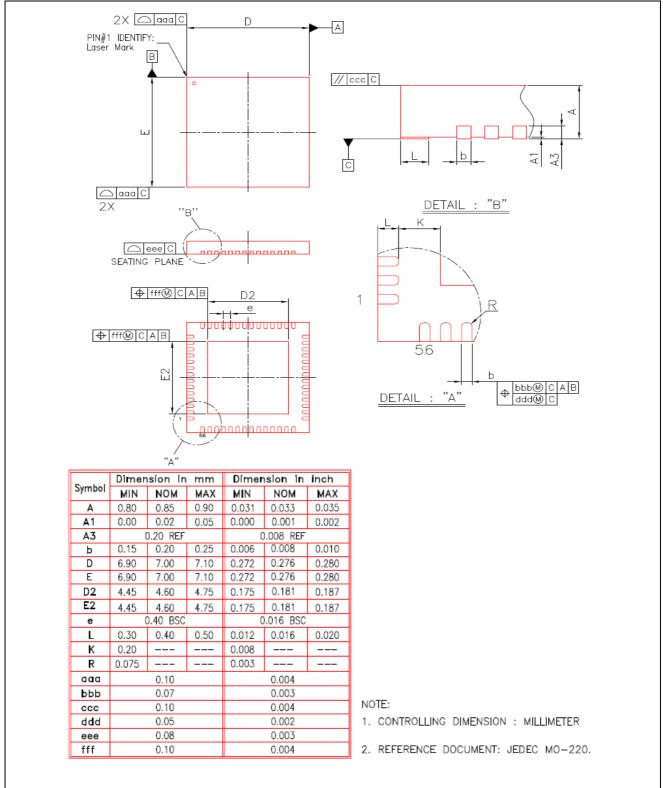
Parameters	MIN	ТҮР	МАХ	Unit
Crystal Frequency		16		MHz
Frequency Tolerence		±20		ppm
Operating Temperature	-20		70	°C
Trimming Capacitance		6.4		pF
Trimming Step Size		0.2		pF

Digital GPIO (2.8V)

Parameters	MIN	TYP	МАХ	Unit
Input Voltage	2.7	3	3.6	V
V _{IH} (Input High Voltage)	2.0		Vdd	V
V _{IL} (Input Low Voltage)	0		0.8	V
Input Reference Resistor				
R _{PU} (Pull-Up Resistor)		50K		Ohm
R _{PD} (Pull-Down Resistor)		50K		Ohm
Output Voltage				
V _{OH} (Output High Voltage)	2.4		Vdd	V
V _{OL} (Output Low Voltage)	0		0.4	V



8 Package Information

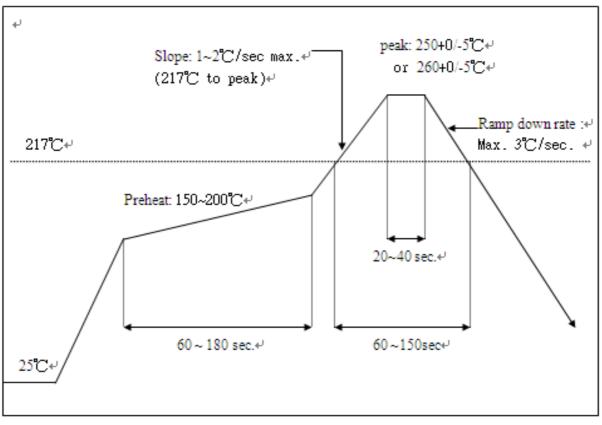




Appendix A. Reflow Profile

- 1.) Follow: IPC/JEDEC J-STD-020 C
- 2.) Condition:

Average ramp-up rate (217°C to peak): $1\sim2°C$ /sec max. Preheat : $150\sim200C \\ 60\sim180$ seconds Temperature maintained above 217°C : $60\sim150$ seconds Time within 5°C of actual peak temperature: $20 \\ 40$ sec. Peak temperature : 250+0/-5°C or 260+0/-5°CRamp-down rate : 3°C/sec. max. Time 25°C to peak temperature : 8 minutes max. Cycle interval : 5 minus



Time (sec)+^j



Appendix B. BQB certification

TPG Project	ISSC Bluetooth 3.0+EDR Single Chip (Component (Tested))					
Qualified Design ID (QD ID)	B016749 Export PIC	<u>S_</u>				
PRD 1.0 ID (QP ID)						
Design Name	ISSC Bluetooth 3.0+EDR	Single Ch	nip			
Wi-Fi® Certification ID						
Subsetted Designs	Date Created	Туре	PICS			
	Jun 28, 2010	Main	PICS			
Member Company	ISSC Technologies Corp.					
Specification Name	3.0					
Core Spec Addenda	N/A					
Design Model Number	IS1XYZ, where X, Y and Z means 1~9					
Hardware Version Number	ISBT_BB_v30					
Software Version Number	ISBT_BB_v30					
Qualification Assessment Date	July/21/2010					
Listing Date	July/21/2010					
Design Description	ISSC Bluetooth 3.0+EDR	Single Ch	nip			
Product Type	Component (Tested)					
Technical Data Sheet (RIN)	** Open Reference Integr	ation Note	es (RIN) **	÷		
Listed By	<u>Charlie Lee</u>					
BQE	Jan-Willem Vonk					
Profile / Protocol	Role / Version (If Any)					
Baseband						
Radio						
Link Manager						